

## DUAL BUS BUFFER

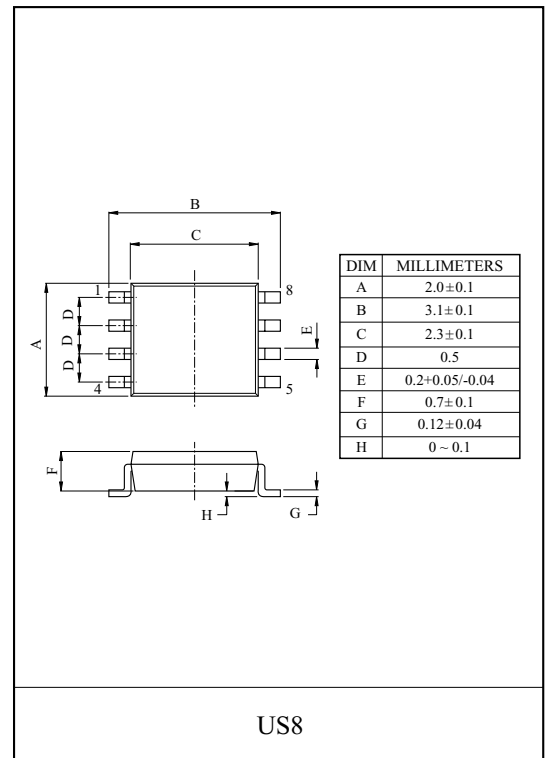
The KIC7W126FK is a high speed C<sup>2</sup>MOS DUAL BUS BUFFERS fabricated with silicon gate C<sup>2</sup>MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the C<sup>2</sup>MOS low power dissipation. The require 3-state control input G to be set low to place the output into the high impedance. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### FEATURES

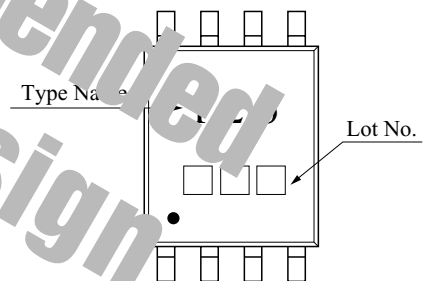
- High Speed :  $t_{pd}=10ns(Typ.)$  at  $V_{CC}=5V$ .
- Low Power Dissipation :  $I_{CC}=2\mu A(Max.)$  at  $T_a=25^\circ C$ .
- High Noise Immunity :  $V_{NIH}=V_{NIL}=28\% V_{CC}(Min.)$ .
- Output Drive Capability : 15 LSTTL Loads.
- Symmetrical Output Impedance :  $|I_{OH}|=|I_{OL}|=10mA(Min.)$ .
- Balanced Propagation Delays :  $t_{pLH} = t_{pHL}$ .
- Wide Operating Voltage Range :  $V_{CC(oper)}=2-6V$ .

### MAXIMUM RATINGS (Ta=25 °C)

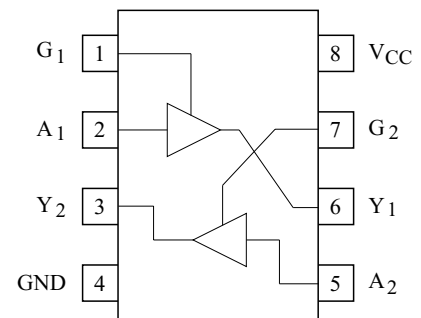
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	$V_{CC}$	-0.5 ~ 7	V
DC Input Voltage	$V_{IN}$	-0.5 ~ $V_{CC}+0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5 ~ $V_{CC}+0.5$	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 20$	mA
DC Output Current	$I_{OUT}$	$\pm 35$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 37.5$	mA
Power Dissipation	$P_D$	200	mW
Storage Temperature	$T_{stg}$	-65 ~ 150	
Lead Temperature (10s)	$T_L$	260	



### MARKING

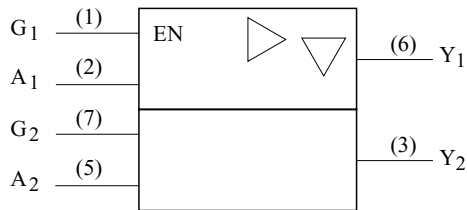


### PIN CONNECTION (TOP VIEW)



# KIC7W126FK

## LOGIC DIAGRAM



## TRUTH TABLE

INPUTS		OUTPUTS
G	A	Y
L	X	Z
H	L	L
H	H	H

X : Don't care

Z : High Impedance

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	$V_{CC}$	2 - 6	V
Input Voltage	$V_{IN}$	0 - $V_{CC}$	V
Output Voltage	$V_{OUT}$	0 - $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40 - 85	
Input Rise and Fall Time	$t_{r/f}$	0 - 500 (V <sub>IN</sub> =5V) 0 - 400 (V <sub>IN</sub> =5V)	ns

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CIRCUIT	TEST CONDITION	Ta=25			Ta=40 - 85			UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.			
High-Level Input Voltage	$V_{IH}$	-	-	2.0	2.5	-	1.5	-	-	V	
				4.5	3.15	-	3.15	-			
				6.0	4.2	-	4.2	-			
Low-Level Input Voltage	$V_{IL}$	-	-	2.0	-	-	0.5	-	0.5	V	
				4.5	-	-	1.35	-	1.35		
				6.0	-	-	1.8	-	1.8		
High-Level Output Voltage	$V_{OH}$	-	$V_{IN}=V_{IH}$	$I_{OH}=-20\mu A$	2.0	1.9	2.0	-	1.9	-	V
				$I_{OH}=-6mA$	4.5	4.4	4.5	-	4.4	-	
				$I_{OH}=-7.8mA$	6.0	5.9	6.0	-	5.9	-	
					4.5	4.18	4.31	-	4.13	-	
Low-Level Output Voltage	$V_{OL}$	-	$V_{IN}=V_{IH}$ or $V_{IL}$	$I_{OL}=20\mu A$	2.0	-	0.0	0.1	-	0.1	V
				$I_{OL}=6mA$	4.5	-	0.0	0.1	-	0.1	
				$I_{OL}=7.8mA$	6.0	-	0.0	0.1	-	0.1	
					4.5	-	0.17	0.26	-	0.33	
	6.0	-	0.18	0.26	-	0.33					
3-State Output Off-State Current	$I_{OZ}$	-	$V_{IN}=V_{IH}$ or $V_{IL}$ $V_{OUT}=V_{CC}$ or GND	6.0	-	-	$\pm 0.5$	-	$\pm 5.0$	$\mu A$	
Input Leakage Current	$I_{IN}$	-	$V_{IN}=V_{CC}$ or GND	6.0	-	-	$\pm 0.1$	-	$\pm 1.0$		
Quiescent Supply Current	$I_{CC}$	-	$V_{IN}=V_{CC}$ or GND	6.0	-	-	2.0	-	20.0		

# KIC7W126FK

## AC ELECTRICAL CHARACTERISTICS (Input, $t_r=t_f=6nS$ )

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	Ta=25			Ta=-40 85		UNIT		
				C <sub>L</sub>	V <sub>CC</sub>	MIN.	TYP.	MAX.		MIN.	MAX.
Output Transition Time	$t_{TLH}$ $t_{THL}$	-	-	50	2.0	-	20	60	-	75	ns
					4.5	-	6	12	-	15	
					6.0	-	5	10	-	13	
Propagation Delay Time	$t_{PLH}$ $t_{PHL}$	-	-	50	2.0	-	30	90	-	115	
					4.5	-	11	18	-	23	
					6.0	-	10	15	-	20	
				150	2.0	-	42	130	-	165	
					4.5	-	14	26	-	33	
					6.0	-	12	22	-	28	
Output Enable Time	$t_{pZL}$ $t_p$	-	R <sub>L</sub> =1k	50	2.0	-	30	90	-	115	
					4.5	-	11	18	-	23	
					6.0	-	10	15	-	20	
				150	2.0	-	42	130	-	165	
					4.5	-	14	26	-	33	
					6.0	-	12	22	-	28	
Output Disable Time	$t_{pLZ}$ $t_{pZ}$	-	R <sub>L</sub> =1	50	2.0	-	24	100	-	125	
					4.5	-	12	20	-	25	
					6.0	-	10	17	-	21	
Input Capacitance	C <sub>IN</sub>	-	-	-	-	5	10	-	10	pF	
Output Capacitance	C <sub>OUT</sub>	-	-	-	-	-	-	-	-		
Power Dissipation Capacitance	C <sub>PD</sub>	-	(Note 1)	-	-	3	-	-	-		

Note 1 : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation :  $I_{CC(opr)} = I_{CCP} + V_{CC} \cdot f_p + I_{CC}/2$  (per gate)